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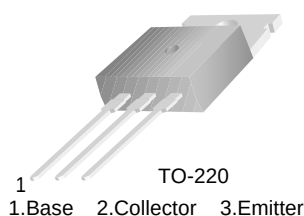
FJP3307D

High Voltage Fast Switching NPN Power Transistor

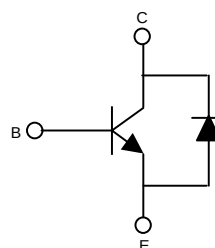
July 2008

Features

- Built-in Diode between Collector and Emitter
- Suitable for Electronic Ballast and Switch Mode Power Supplies



Internal Schematic Diagram



Absolute Maximum Ratings

Symbol	Parameter	Value	Units
V_{CBO}	Collector-Base Voltage	700	V
V_{CEO}	Collector-Emitter Voltage	400	V
V_{EBO}	Emitter-Base Voltage	9	V
I_C	Collector Current (DC)	8	A
I_{CP}	* Collector Current (Pulse)	16	A
I_B	Base Current (DC)	4	A
P_C	Collector Dissipation ($T_C = 25^\circ\text{C}$)	80	W
T_J	Junction Temperature	150	$^\circ\text{C}$
T_{STG}	Storage Temperature	-55 ~ 150	$^\circ\text{C}$

* Pulse Test: PW = 300ms, Duty Cycle = 2% Pulsed

Electrical Characteristics $T_C = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Conditions	Min.	Typ.	Max	Units
BV_{CBO}	Collector-Base Breakdown Voltage	$I_C = 500\mu\text{A}$, $I_E = 0$	700			V
BV_{CEO}	Collector-Emitter Breakdown Voltage	$I_C = 5\text{mA}$, $I_B = 0$	400			V
BV_{EBO}	Emitter-Base Breakdown Voltage	$I_E = 500\mu\text{A}$, $I_C = 0$	9			V
I_{EBO}	Emitter Cut-off Current	$V_{EB} = 9\text{V}$, $I_C = 0$			1	mA
h_{FE1} h_{FE2}	DC Current Gain	$V_{CE} = 5\text{V}$, $I_C = 2\text{A}$ $V_{CE} = 5\text{V}$, $I_C = 5\text{A}$	8 5		40 30	
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage	$I_C = 2\text{A}$, $I_B = 0.4\text{A}$			1	V
		$I_C = 5\text{A}$, $I_B = 1\text{A}$			2	V
		$I_C = 8\text{A}$, $I_B = 2\text{A}$			3	V

Symbol	Parameter	Conditions	Min.	Typ.	Max	Units
$V_{BE(sat)}$	Base-Emitter Saturation Voltage	$I_C = 2A, I_B = 0.4A$			1.2	V
		$I_C = 5A, I_B = 1A$			1.6	V
V_F	Diode Forward Voltage	$I_C = 3A$			2.5	V
C_{ob}	Output Capacitance	$V_{CB} = 10V, I_E = 0, f = 1MHz$		60		pF
t_{STG}	Storage Time	$V_{CC} = 125V, I_C = 5A$ $I_{B1} = -I_{B2} = 1A, R_L = 50\Omega$			3	μs
t_F	Fall Time				0.7	μs
t_{STG}	Storage Time	$V_{CC} = 30V, I_C = 5A, L=200\mu H$ $I_{B1}=1A, R_{BB} = 0\Omega, V_{BE(OFF)} = -5V$ $V_{CLAMP} = 250V$			2.3	μs
t_F	Fall Time				150	ns

* Pulse test: PW = 300 μs , Duty cycl e= 2%

h_{FE} Classification

Classification	H1	H2
h_{FE1}	15 ~ 28	26 ~ 39

Typical Characteristics

Figure 1. Static Characteristic

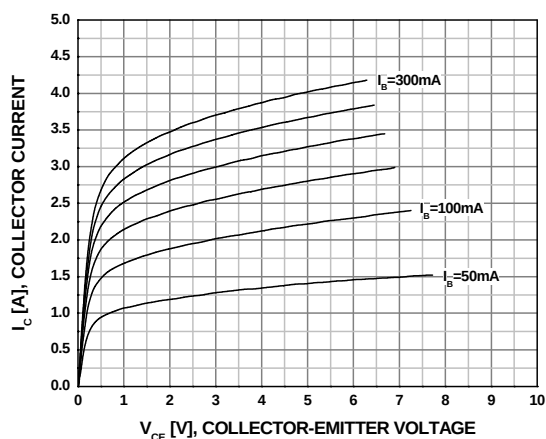


Figure 2. DC Current Gain (H1 Grade)

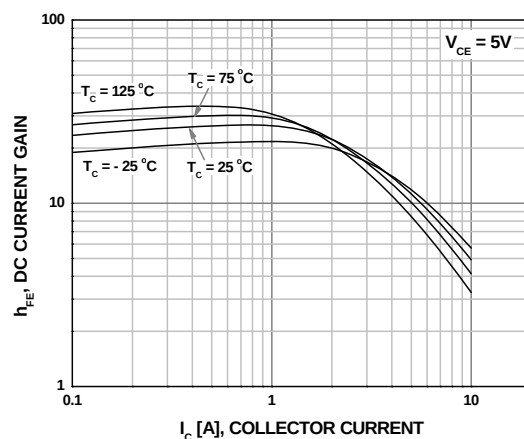


Figure 3. DC Current Gain (H2 Grade)

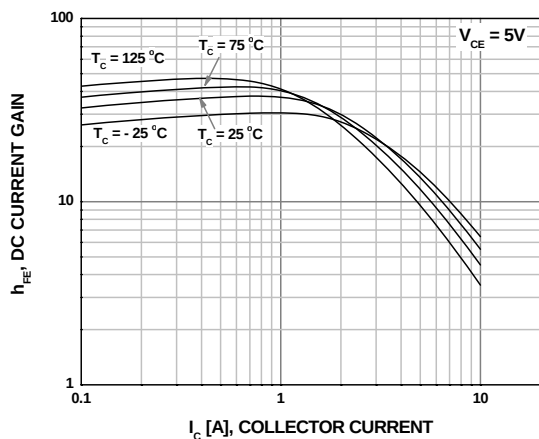


Figure 4. Collector-Emitter Saturation Voltage

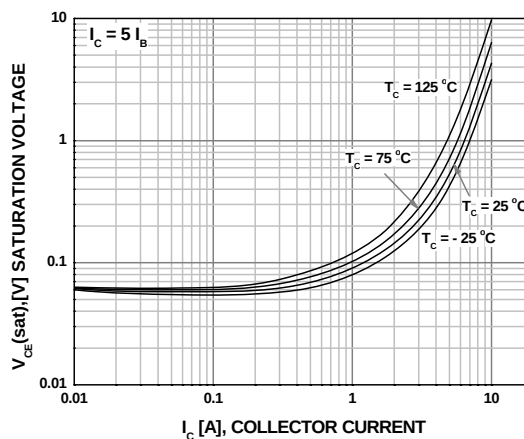


Figure 5. Base-Emitter Saturation Voltage

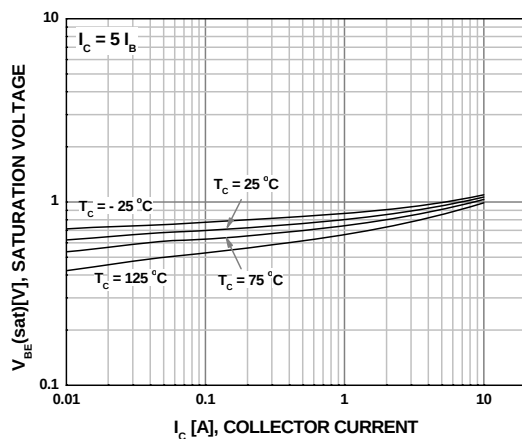
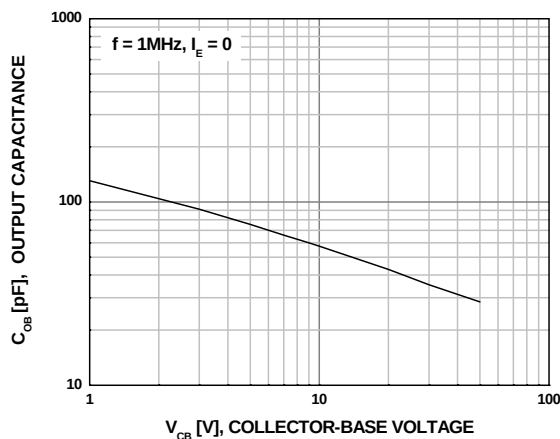


Figure 6. Output Capacitance



Typical Characteristics (Continued)

Figure 7. Power Derating

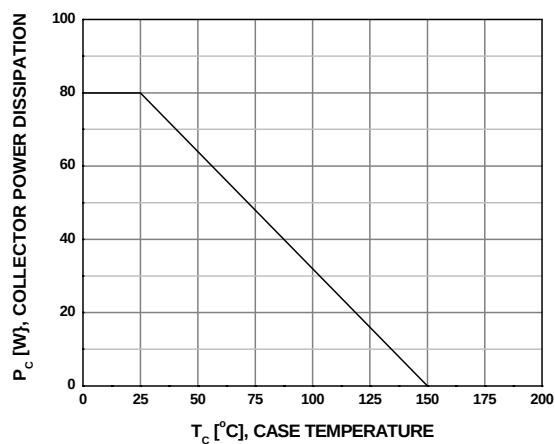


Figure 8. Reverse Biased Safe Operating Area

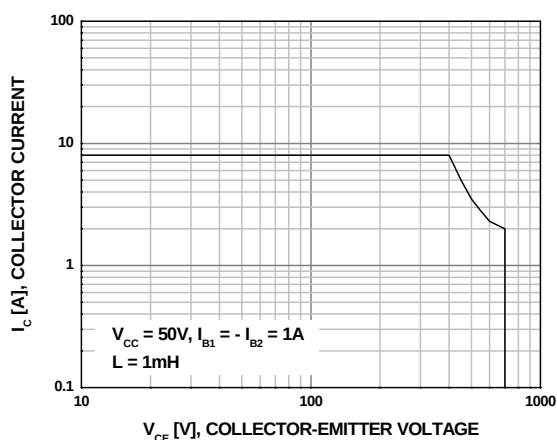
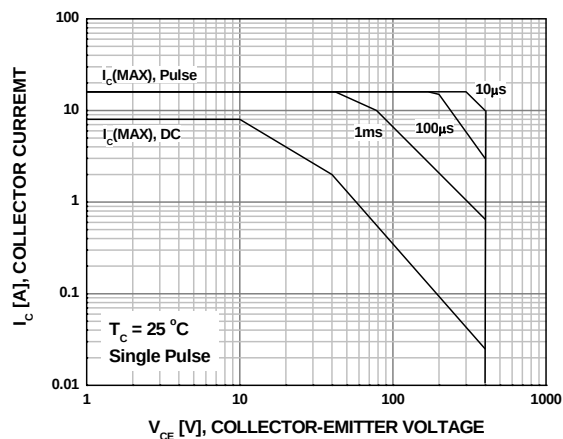
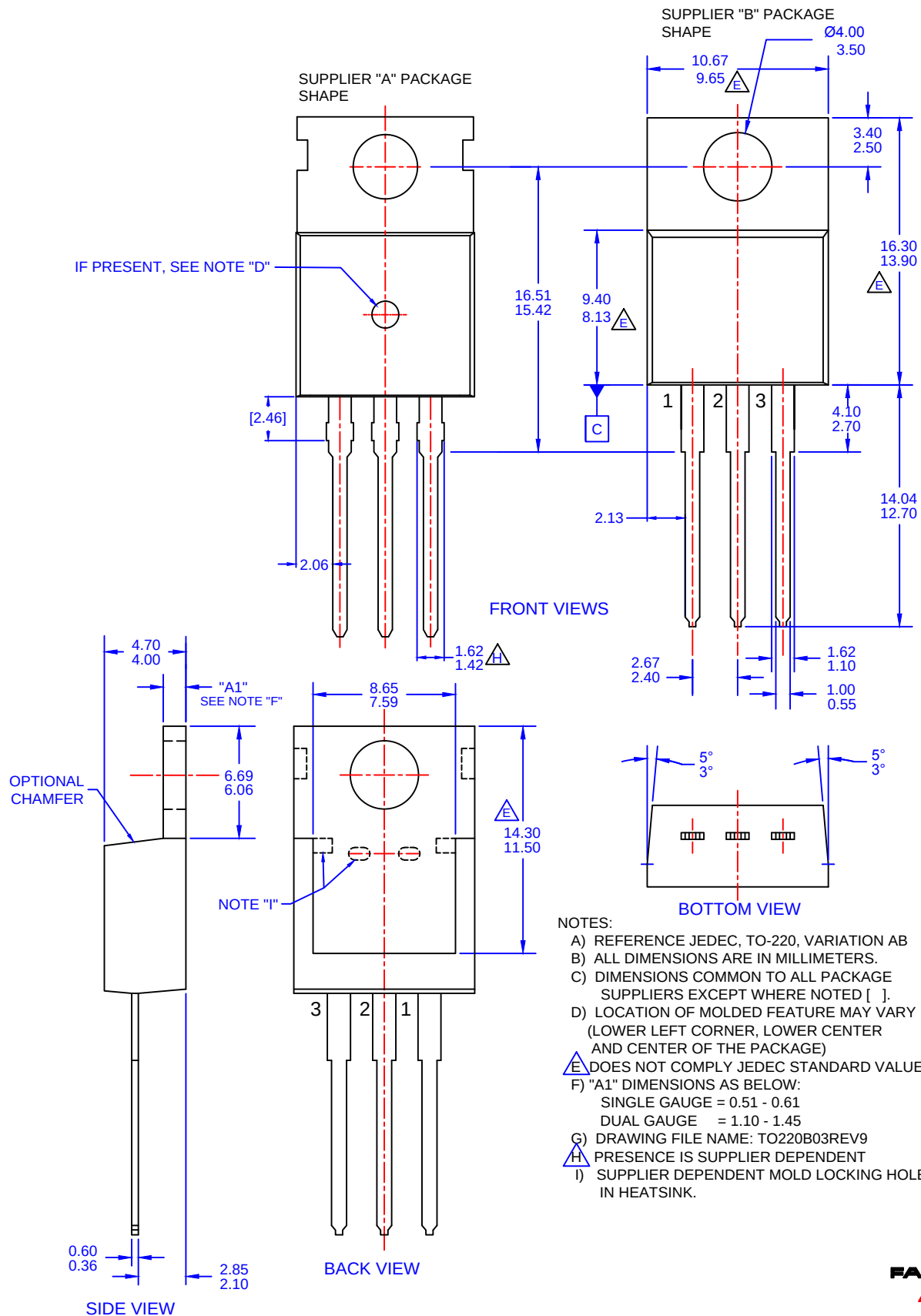


Figure 9. Forward Biased Safe Operating Area





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